

Publikačný seminár

A. Rosová:

In(Ga)N 3D growth on GaN-buffered on-axis and off-axis (0001) sapphire substrates by MOCVD
Nanomaterials

J. Osvald:

Intersection of 4H-SiC Schottky diodes I–V curves due to temperature dependent series resistance
Semicond. Sci. Technol.

F. Gömöry:

Formation of hot spots in coated conductors during static and dynamic DC loading
Probability of premature quenching of HTS coil due to local reduction of critical current *IEEE Trans. Applied Supercond.*

Čas: 25. 11. 2022 o 10:00 hod. Miesto: veľká zasadačka EIÚ SAV, v.v.i., miestnosť 101